



DMN3008SFGQ

30V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I⊳ Max Tc = +25°C
	4.4mΩ @ V _{GS} = 10V	62A
30V	5.5mΩ @ V _{GS} = 4.5V	56A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Backlighting
- Power-management functions
- DC-DC converters

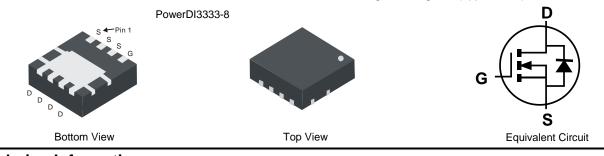
Features and Benefits

- Low R_{DS(ON)} Ensures On-State Losses Are Minimized
- Small, Form Factor Thermally Efficient Package Enables Higher
 Density End Products
- Occupies Only 33% of the Board Area Occupied by SO-8 Enabling Smaller End Products
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN3008SFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: PowerDI[®]3333-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.034 grams (Approximate)



Ordering Information (Note 4)

Part Number	Package	Packing		
Fait Nulliber	Fackage	Qty.	Carrier	
DMN3008SFGQ-7	PowerDI3333-8	2,000	Tape & Reel	
DMN3008SFGQ-13	PowerDI3333-8	3,000	Tape & Reel	

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

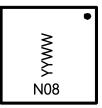
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





N08 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 23 = 2023) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage		V _{DSS}	30	V	
Gate-Source Voltage			Vgss	±20	V
	Steady State	T _A = +25°C T _A = +70°C	ID	17.6 14.1	А
Continuous Drain Current (Note 6) V_{GS} = 10V	t < 10s	T _A = +25°C T _A = +70°C	lo	23.0 18.4	А
	Steady State	Tc = +25°C Tc = +70°C	lo	62 50	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%		Ідм	80	А	
Maximum Continuous Body Diode Forward Current	ls	2	А		
Avalanche Current, L = 0.1mH	I _{AS}	45	А		
Avalanche Energy, L = 0.1mH			Eas	101	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Total Dower Dissipation (Nato 5)	T _A = +25°C	D-	0.9	W	
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.6		
Thermal Registence, Junction to Ambient (Note E)	Steady State	Davi	134	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)	t < 10s	Reja	79	°C/W	
Total Power Dissipation (Note 6)	T _A = +25°C	Da	2.1	W	
	T _A = +70°C	PD	1.3	vv	
Thermal Desistance, Junction to Ambient (Note 6)	Steady State	Devi	58	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t < 10s	Reja	34	°C/W	
Thermal Resistance, Junction to Case (Note 6)		R _{0JC}	4.8	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

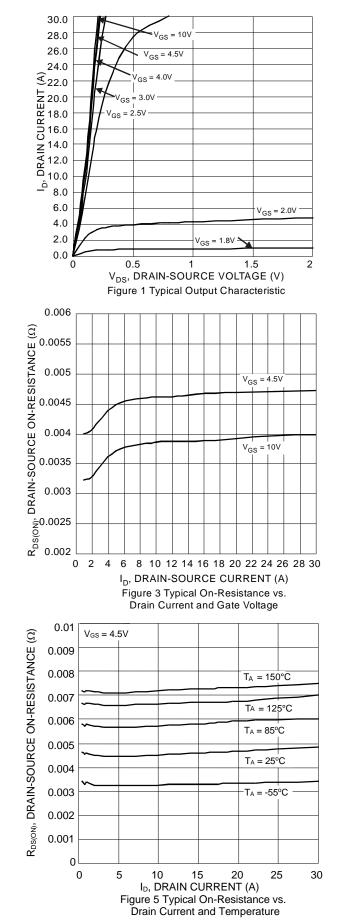
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

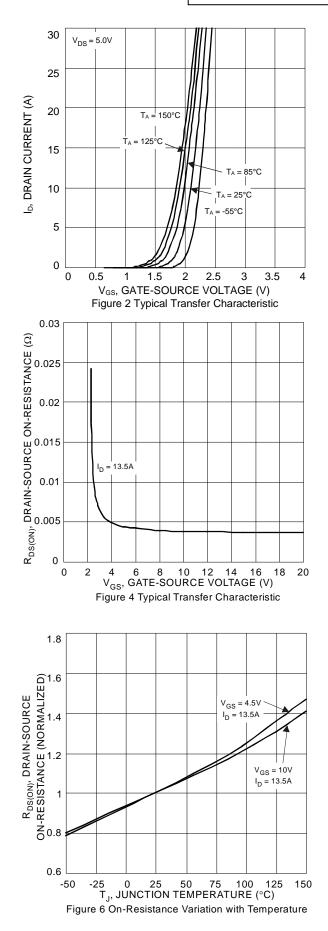
			-				
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	30	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	_	—	10	μA	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(th)	1	—	2.3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Deserve	_	3.9	4.4	mΩ	V _{GS} = 10V, I _D = 13.5A	
Static Drain-Source On-Resistance	RDS(ON)	_	4.6	5.5	11152	V _{GS} = 4.5V, I _D = 13.5A	
Diode Forward Voltage	V _{SD}	_	0.75	1.2	V	$V_{GS} = 0V, I_S = 1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	—	3,690	-	pF		
Output Capacitance	Coss	_	530	—	pF	Vps = 10V, Vgs = 0V, f = 1MHz	
Reverse Transfer Capacitance	Crss	_	459	—	pF		
Gate Resistance	Rg	_	0.9	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	41	—	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	_	86	—	nC		
Gate-Source Charge	Q _{gs}	—	9.2	—	nC	V _{DS} = 24V, I _D = 27A	
Gate-Drain Charge	Q _{gd}	_	18.6	—	nC		
Turn-On Delay Time	tD(ON)	_	5.7	—	ns		
Turn-On Rise Time	tR		14.0	—	ns	$V_{DD} = 15V, V_{GS} = 10V,$	
Turn-Off Delay Time	tD(OFF)		63.7	_	ns	$R_{L} = 1.11\Omega, R_{G} = 4.7\Omega,$	
Turn-Off Fall Time	tF	_	28.4	_	ns	I _D = 13.5A	
Reverse Recovery Time	trr		19.3	_	ns		
Reverse Recovery Charge	Q _{RR}	_	10.7	_	nC	$I_F = 13.5A, di/dt = 100A/\mu s$	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect. Notes:

8. Guaranteed by design. Not subject to product testing.

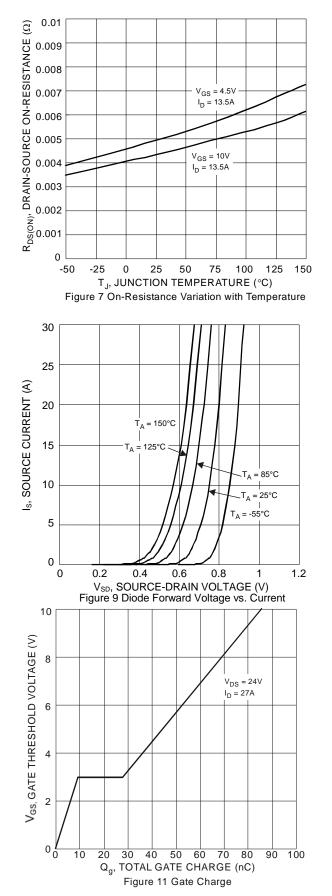


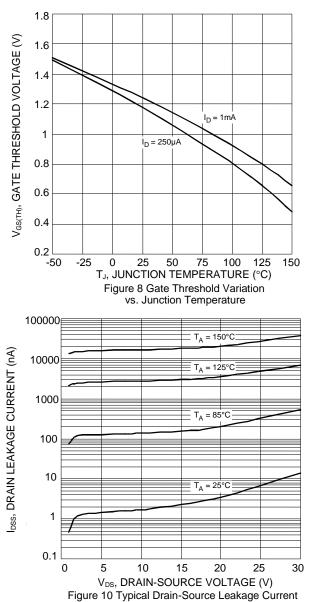




DMN3008SFGQ Document number: DS38901 Rev. 2 - 2 3 of 7 www.diodes.com



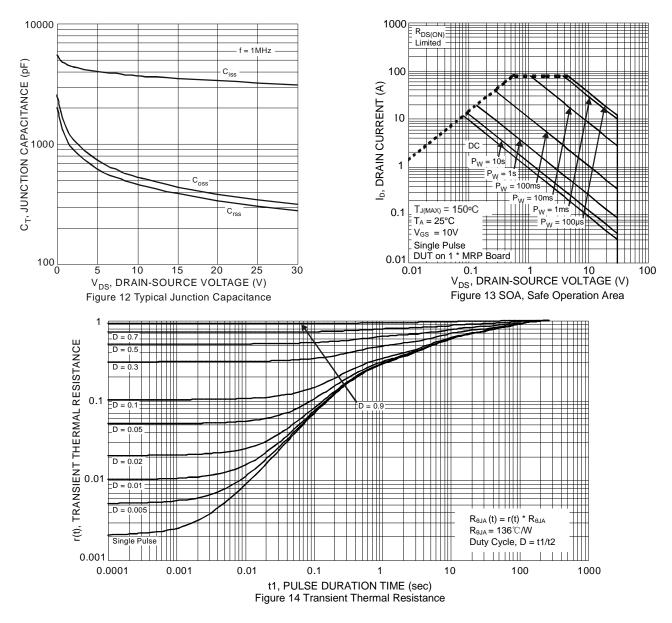




vs. Voltage



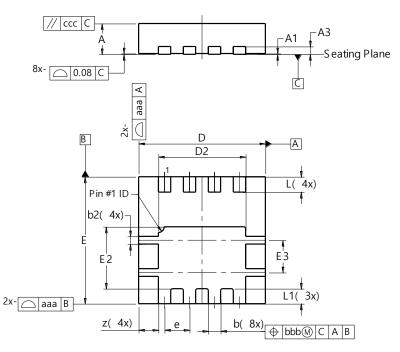
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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

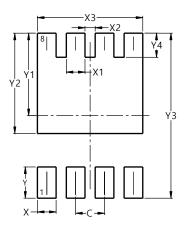


PowerDI3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
A3	-	-	0.203		
b	0.27	0.37	0.32		
b2	-	_	0.20		
D	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
Е	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
E3	0.79	0.89	0.84		
e	-	-	0.65		
1	0.35	0.45	0.40		
L1	1	1	0.39		
z	-	-	0.515		
aaa	0.25				
bbb	0.10				
CCC	0.10				
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
X3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540

PowerDI3333-8



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